

Vishay Siliconix

N-Channel 75 V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}$ (Ω) I_{D} (A)		Q _g (Typ)	
75	0.0048 at V_{GS} = 10 V	90 ^d	105	
	0.006 at V_{GS} = 8 V	90 ^d	105	

TO-220AB

G D S

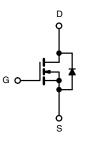
Top View Ordering Information: SUP90N08-4m8P-E3 (Lead (Pb)-free)

FEATURES

- TrenchFET[®] Power MOSFET
- 175 °C Junction Temperature
- 100 % UIS Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Power Supply
 - Half-Bridge
 - Secondary Synchronous Rectification
- Industrial



N-Channel MOSFET

ABSOLUTE MAXIMUM RATING	S (T _C = 25 °C, unless oth	erwise noted)			
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	75	V	
Gate-Source Voltage		V _{GS}	± 20	v	
Continuous Drain Current (T _J = 175 °C)	T _C = 25 °C	1-	90 ^d		
	T _C = 70 °C	I _D	90 ^d	А	
Pulsed Drain Current		I _{DM}	240		
Avalanche Current		I _{AS}	70		
Single Pulse Avalanche Energy ^a	L = 0.1 mH	E _{AS}	245	mJ	
Maximum Power Dissipation ^a	T _C = 25 °C	Р	300 ^b	w	
	T _A = 25 °C ^c	– P _D –	3.75	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Limit	Unit	
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	40	°C/W	
Junction-to-Case (Drain)	R _{thJC}	0.5		

Notes:

a. Duty cycle \leq 1 %.

b. See SOA curve for voltage derating.

c. When mounted on 1" square PCB (FR-4 material).

d. Package limited.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V_{DS}	$V_{DS} = 0 \text{ V}, \text{ I}_{D} = 250 \mu\text{A}$	75			v
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	2		4	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 250	nA
Zero Gate Voltage Drain Current		$V_{DS} = 75 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ
	I _{DSS}	$V_{DS} = 75 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$			50	
		V_{DS} = 75 V, V_{GS} = 0 V, T_{J} = 150 °C			250	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 10 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	70			А
Drain-Source On-State Resistance ^a		V _{GS} = 10 V, I _D = 20 A		0.004	0.0048	- Ω
	в	V_{GS} = 10 V, I _D = 20 A, T _J = 125 °C			0.0096	
	R _{DS(on)}	$V_{GS} = 8 \text{ V}, \text{ I}_{D} = 20 \text{ A}, \text{ T}_{J} = 150 ^{\circ}\text{C}$			0.0106	
		$V_{GS} = 8 V, I_{D} = 20 A$		0.0046	0.006	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		58		S
Dynamic ^b						
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 40 V, f = 1 MHz		6460		pF
Output Capacitance	C _{oss}			571		
Reverse Transfer Capacitance	C _{rss}			275		
Total Gate Charge ^c	Qg	V _{DS} = 30 V, V _{GS} = 10 V, I _D = 85 A		105	160	nC
Gate-Source Charge ^c	Q _{gs}			32		
Gate-Drain Charge ^c	Q _{gd}			28		
Gate Resistance	R _q	f = 1 MHz		1.3	2.6	Ω
Turn-On Delay Time ^c	t _{d(on)}	V_{DD} = 30 V, R _L = 0.4 Ω I _D ≅ 85 A, V _{GEN} = 10 V, R _g = 1 Ω		23	35	ns
Rise Time ^c	t _r			17	26	
Turn-Off Delay Time ^c	t _{d(off)}			34	52	
Fall Time ^c	t _f			8	15	
Source-Drain Diode Ratings and Cha	aracteristics (T _C = 25 °C) ^b			<u> </u>	
Continuous Current	I _S				85	
Pulsed Current	I _{SM}				240	A
Forward Voltage ^a	V _{SD}	I _F = 30 A, V _{GS} = 0 V		0.85	1.5	V
Reverse Recovery Time	t _{rr}			68	100	ns
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = 75 A, dl/dt = 100 A/μs		2.6	4	А
Reverse Recovery Charge	Q _{rr}			88	132	nC

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

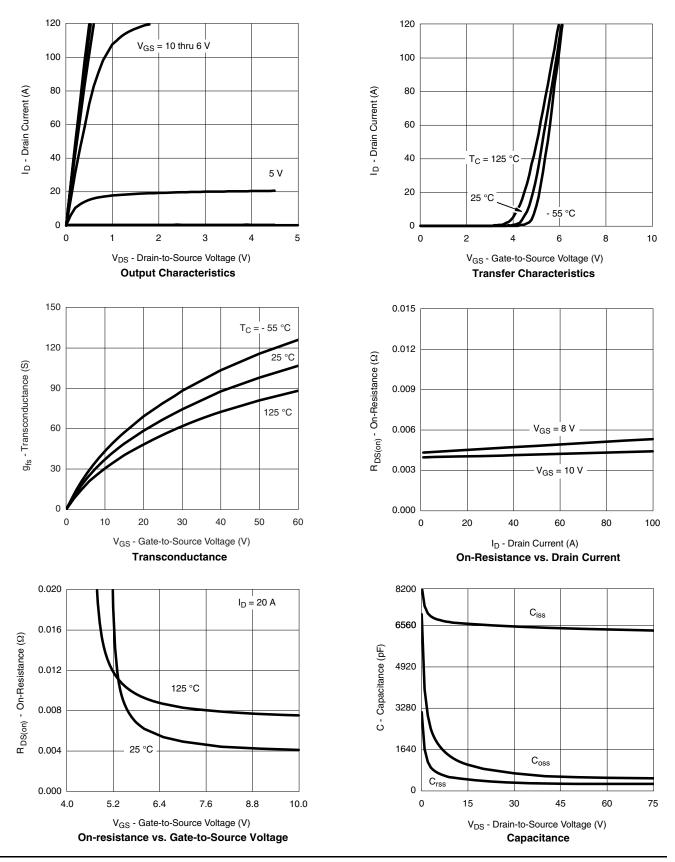
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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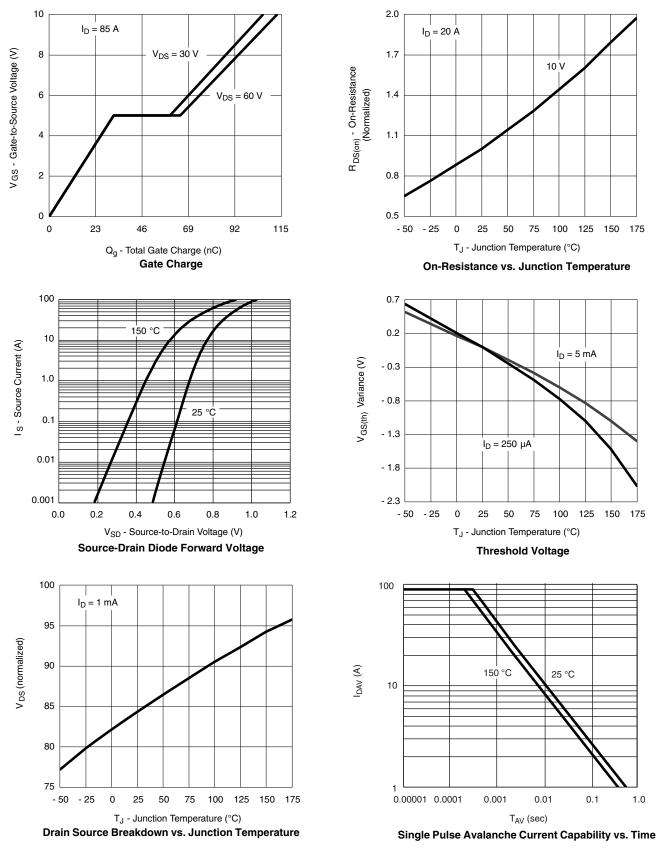
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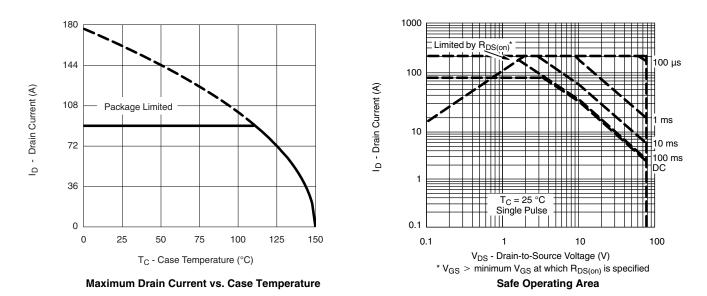
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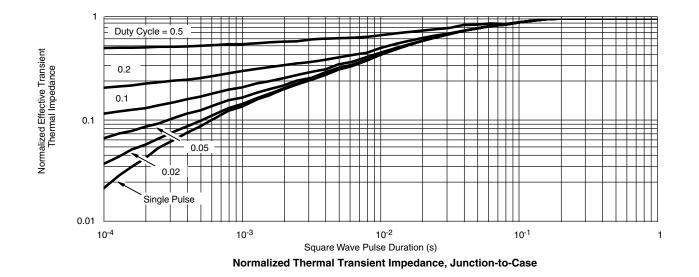


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